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**Cheng**

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(54) **SYSTEMS AND METHODS OF  
PHASE-LOCKED LOOP INVOLVING  
CLOSED-LOOP, CONTINUOUS FREQUENCY  
RANGE, AUTO CALIBRATION AND/OR  
OTHER FEATURES**

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5,942,949	A	8/1999	Wilson et al.
6,114,920	A	9/2000	Moon et al.
6,175,282	B1	1/2001	Yasuda
6,661,267	B2	12/2003	Walker et al.
6,683,502	B1	1/2004	Groen et al.
6,816,019	B2	11/2004	Delbo' et al.
6,838,951	B1	1/2005	Nieri et al.
6,933,789	B2	8/2005	Molnar et al.
6,998,922	B2	2/2006	Jensen et al.
7,002,416	B2	2/2006	Pettersen et al.
7,019,569	B2	3/2006	Fan-Jiang
7,046,093	B1	5/2006	McDonagh et al.
7,047,146	B2	5/2006	Chuang et al.
7,099,643	B2	8/2006	Lin
7,141,961	B2	11/2006	Hirayama et al.
7,233,214	B2	6/2007	Kim et al.
7,263,152	B2	8/2007	Miller et al.
7,269,402	B2	9/2007	Uozumi et al.
7,330,080	B1	2/2008	Stoiber et al.
7,352,249	B2	4/2008	Balboni et al.
7,355,482	B2	4/2008	Meltzer
7,463,101	B2	12/2008	Tung
7,538,623	B2	5/2009	Jensen et al.
7,659,783	B2	2/2010	Tai

(Continued)

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14, 2013.

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**H03L 7/085** (2006.01)  
**H03L 7/08** (2006.01)

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**CPC . H03L 7/085** (2013.01); **H03L 7/08** (2013.01)

(58) **Field of Classification Search**  
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See application file for complete search history.

(56) **References Cited**

#### U.S. PATENT DOCUMENTS

4,677,394	A	6/1987	Vollmer
5,696,468	A	12/1997	Nise
5,748,044	A	5/1998	Xue

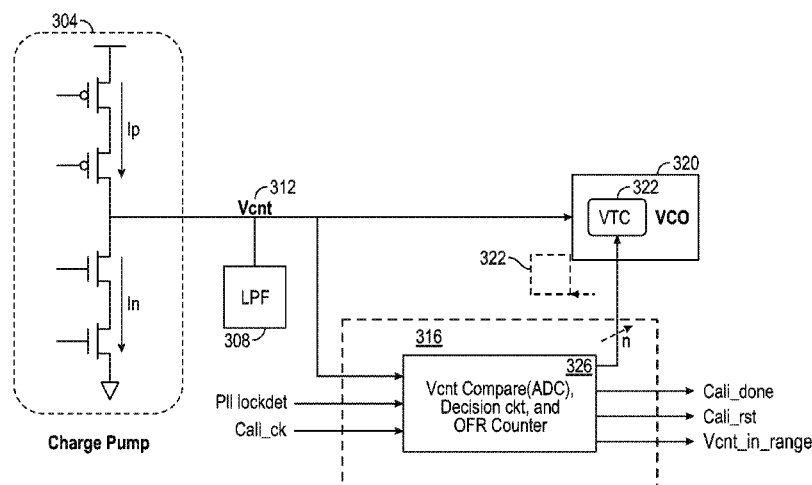
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(57) **ABSTRACT**

Systems and methods involving phase-locked-loop (PLL) circuitry are disclosed. In one illustrative implementation, a PLL circuit device may comprise voltage controlled oscillator (VCO) circuitry having a bias signal that sets a frequency range, circuitry that shifts the VCO circuitry to operate in one of the frequency ranges, and other circuitry to compare/calibrate signals and/or set the bias current. According to further implementations, as a function of operation of the circuitry, an operating frequency range of the VCO circuitry may be shifted to a different operating frequency range, and closed-loop, continuous frequency range, auto-calibration or other features may be provided.

**95 Claims, 13 Drawing Sheets**



(56)

**References Cited**

U.S. PATENT DOCUMENTS

7,663,415 B2 2/2010 Chatterjee et al.  
 7,719,330 B2 5/2010 Lin et al.  
 7,746,181 B1 6/2010 Moyal  
 7,746,182 B2 6/2010 Ramaswamy et al.  
 7,760,032 B2 7/2010 Ardehali  
 7,760,040 B2 7/2010 Zhang et al.

7,876,163 B2 1/2011 Hachigo  
 7,956,695 B1 6/2011 Ding et al.  
 8,008,956 B1 8/2011 Shin et al.  
 8,044,724 B2 10/2011 Rao et al.  
 8,174,332 B1 5/2012 Lombaard et al.  
 2004/0160250 A1 \* 8/2004 Kim et al. .... 327/158  
 2006/0119443 A1 6/2006 Azam et al.  
 2009/0296869 A1 12/2009 Chao et al.  
 2010/0271138 A1 10/2010 Thakur et al.

\* cited by examiner

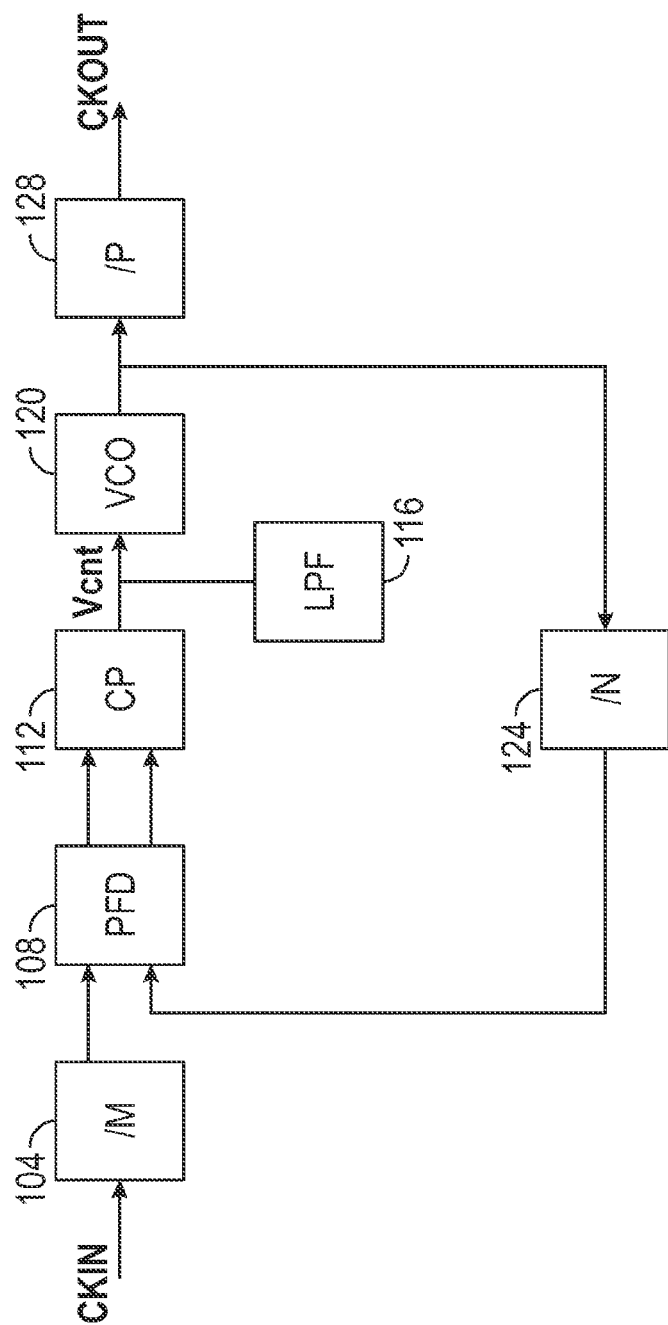


FIG. 1

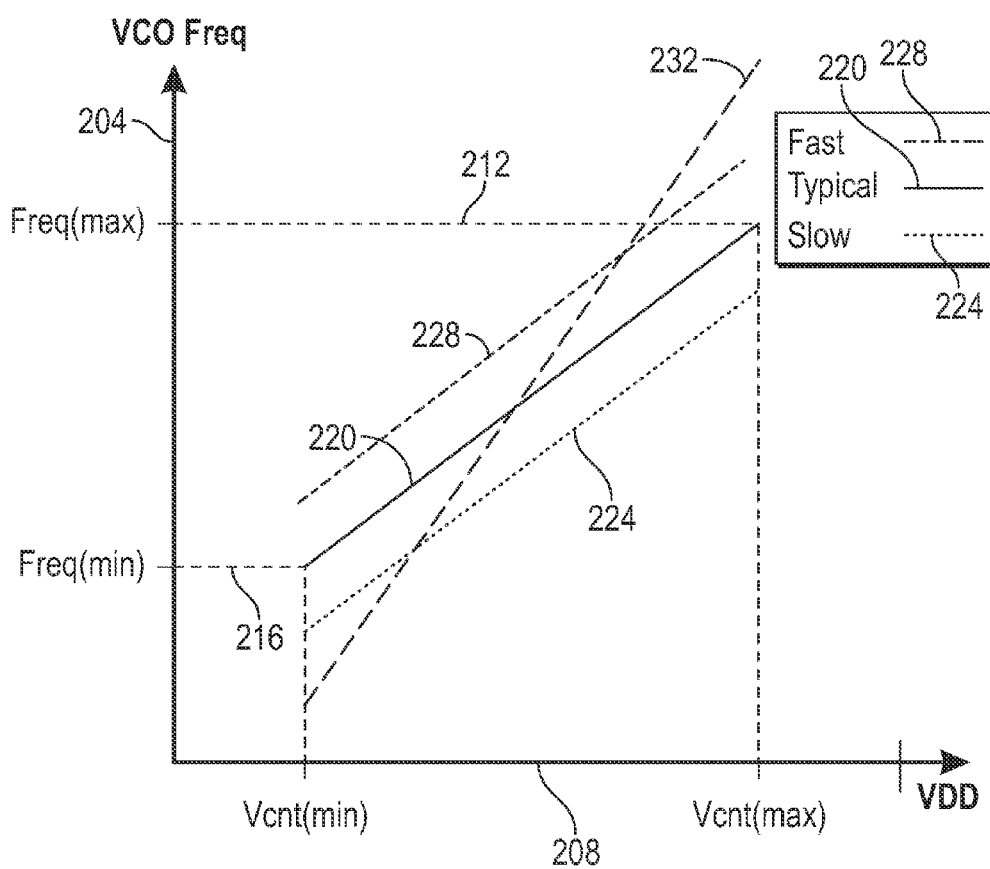
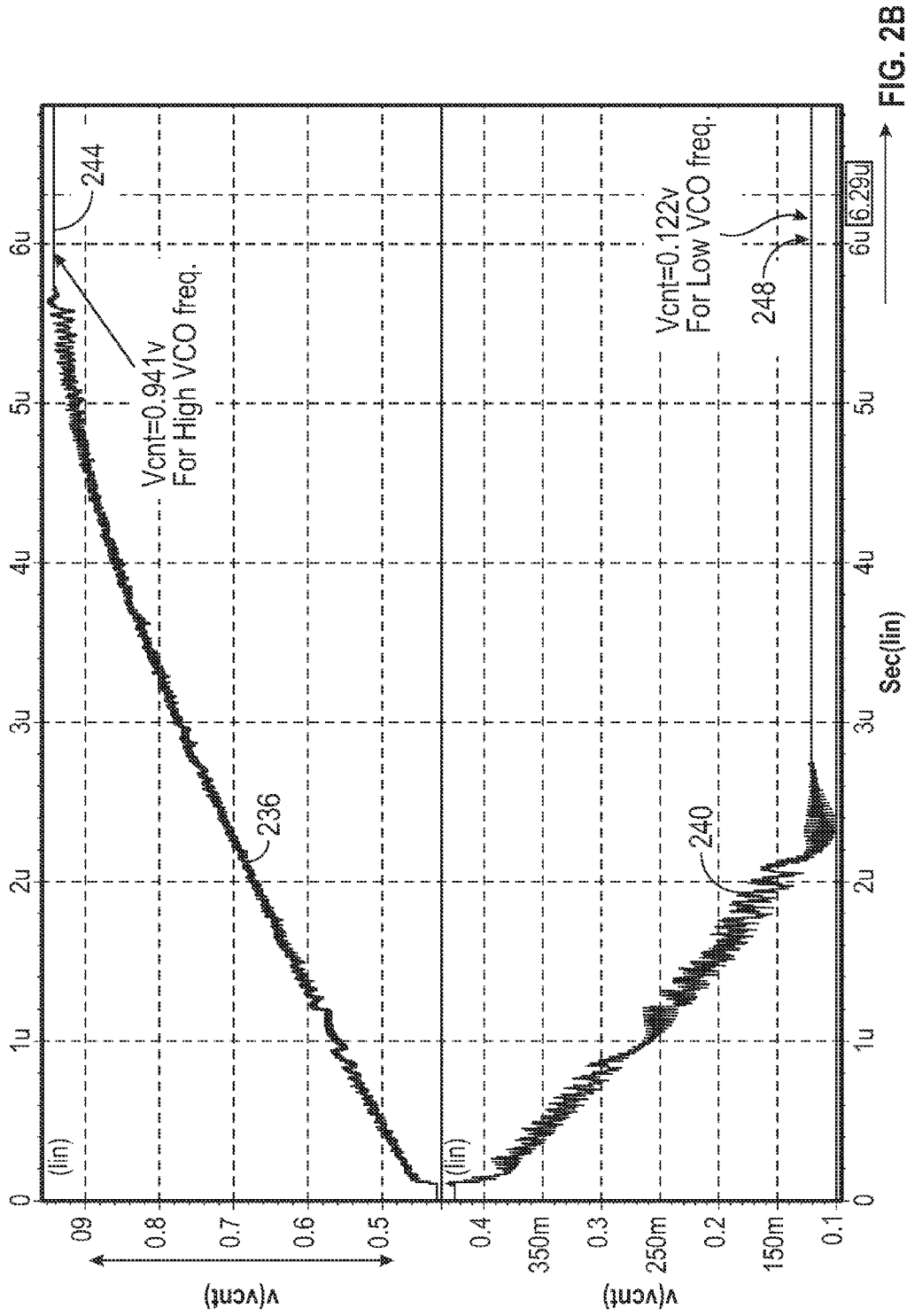


FIG. 2A



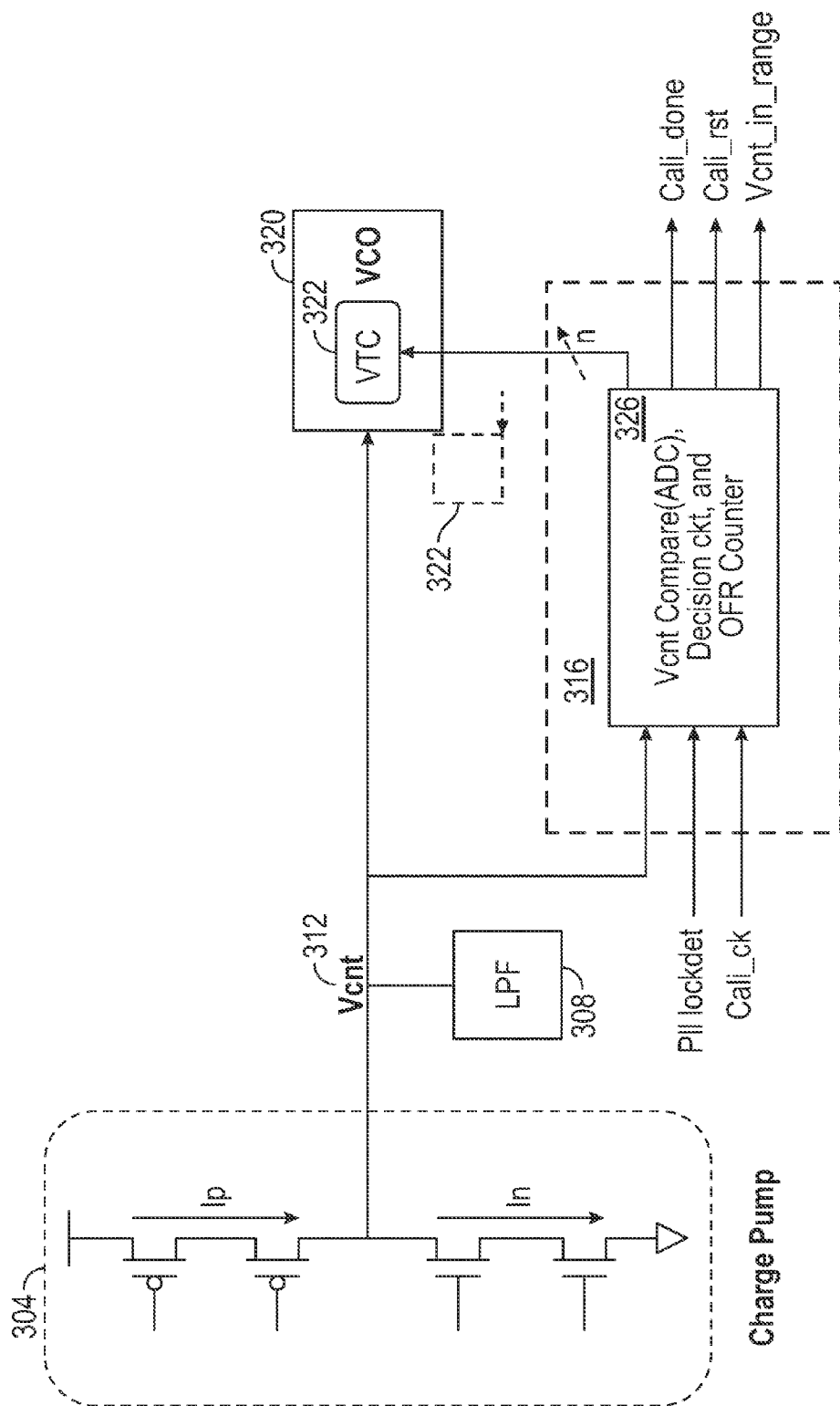


FIG. 3

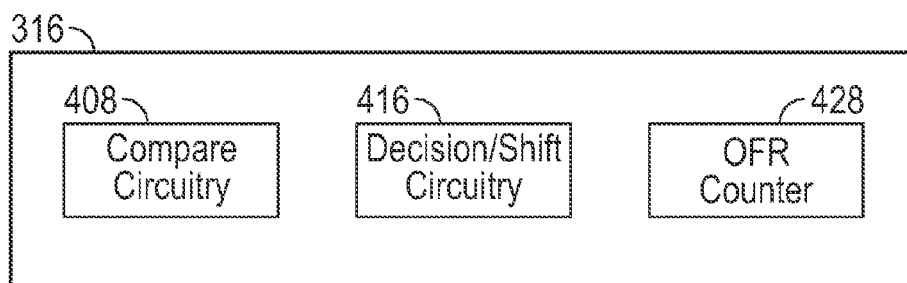


FIG. 4

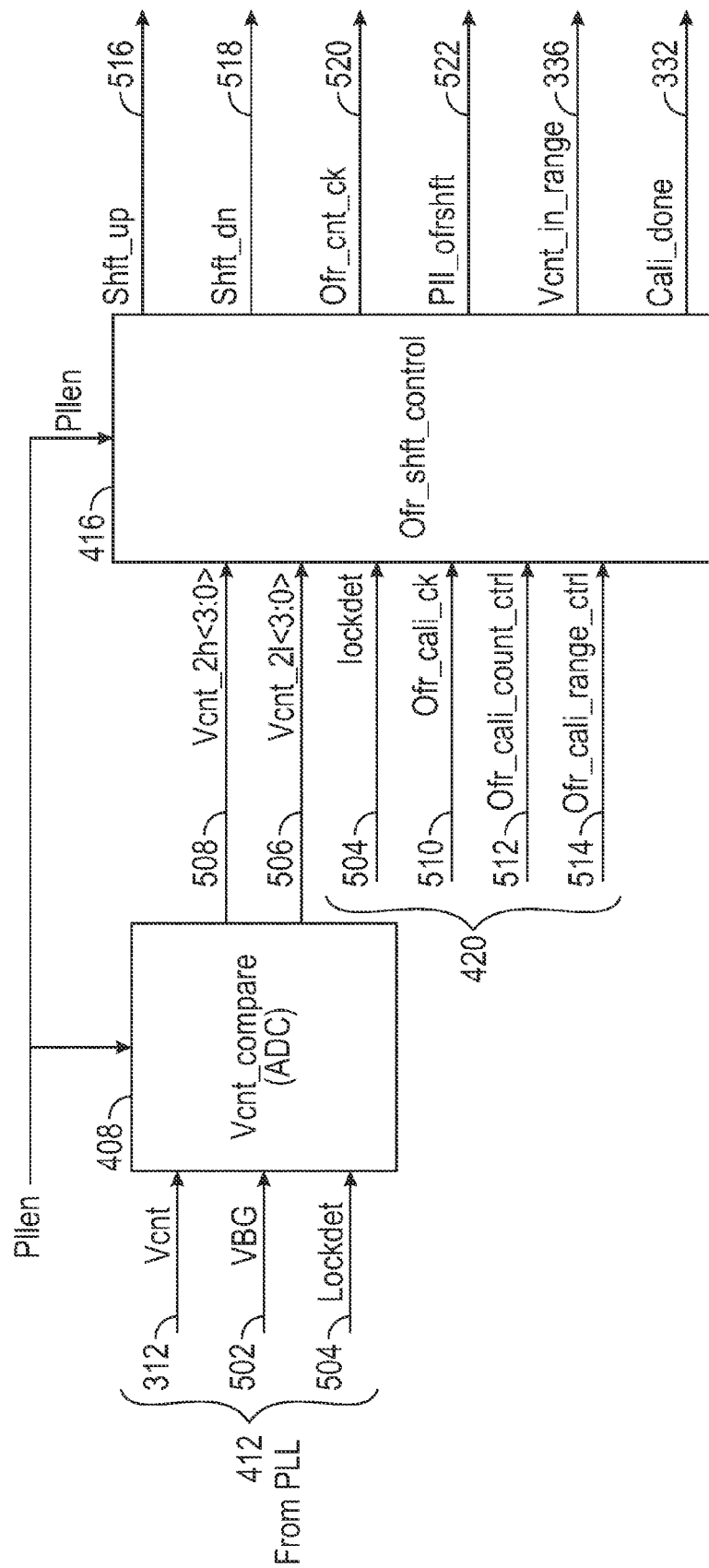


FIG. 5



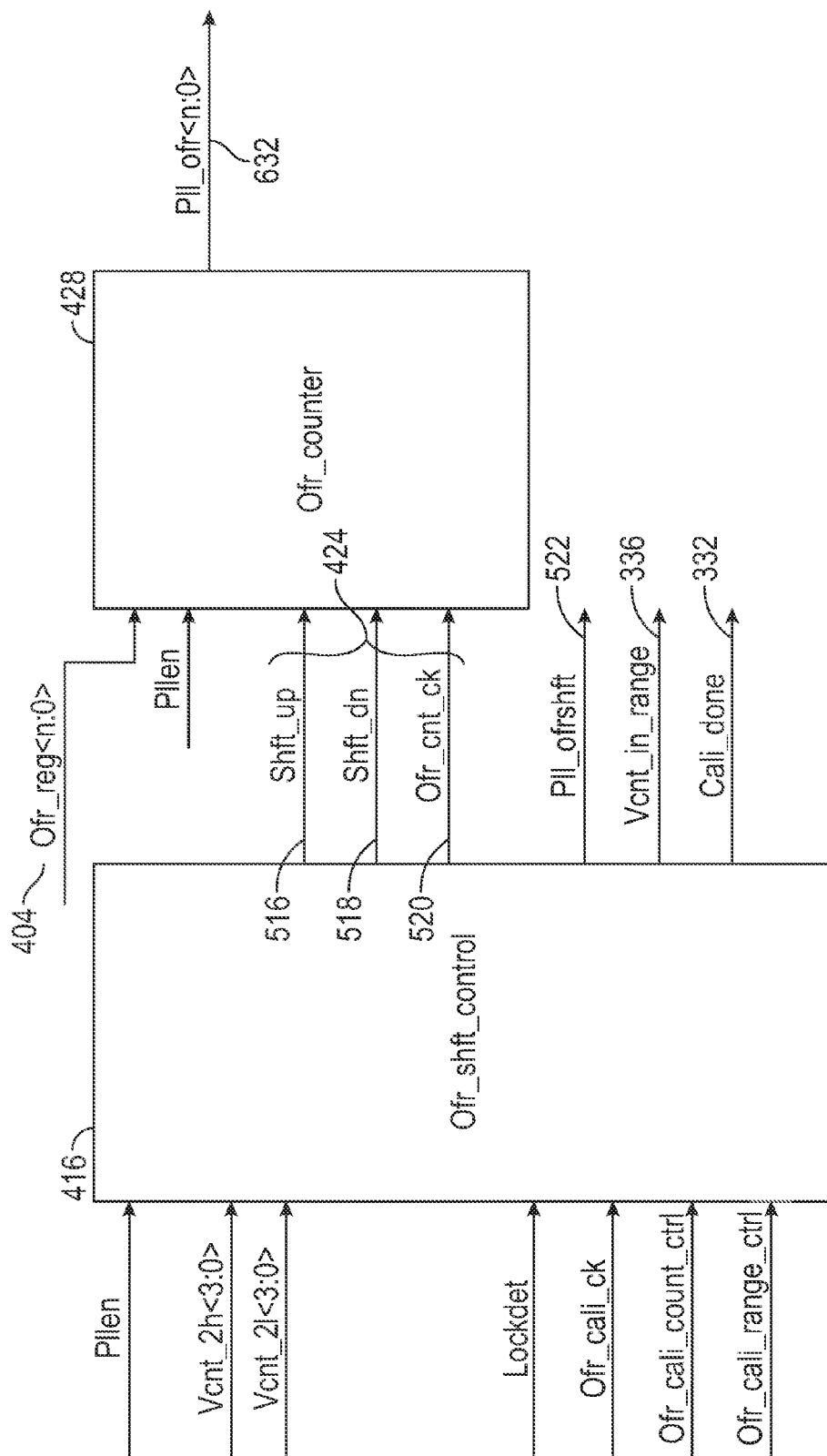


FIG. 6

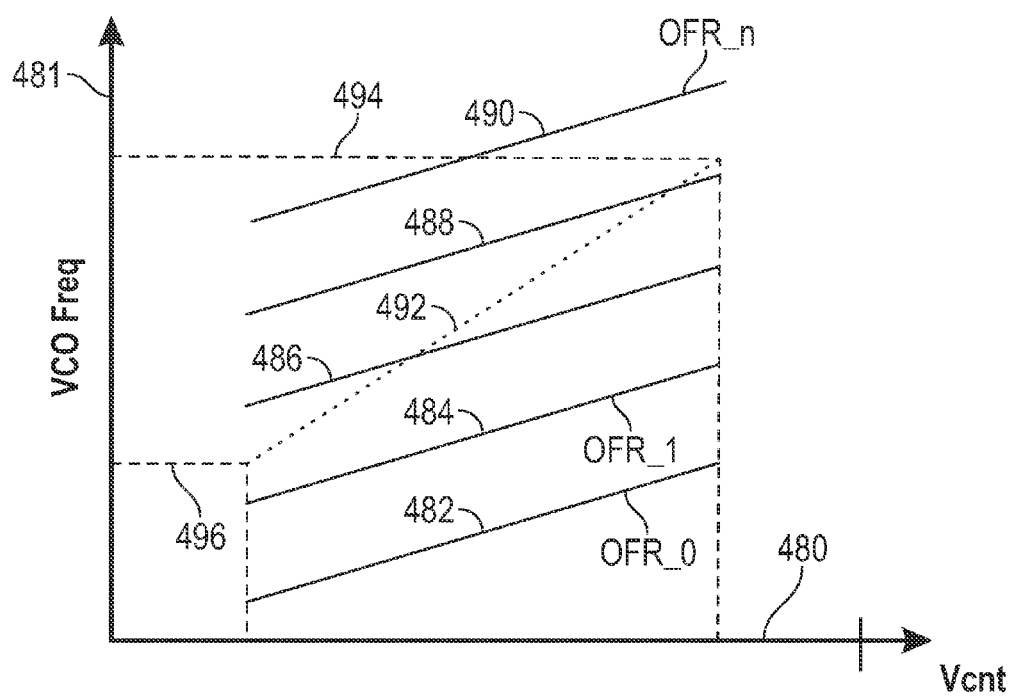


FIG. 7

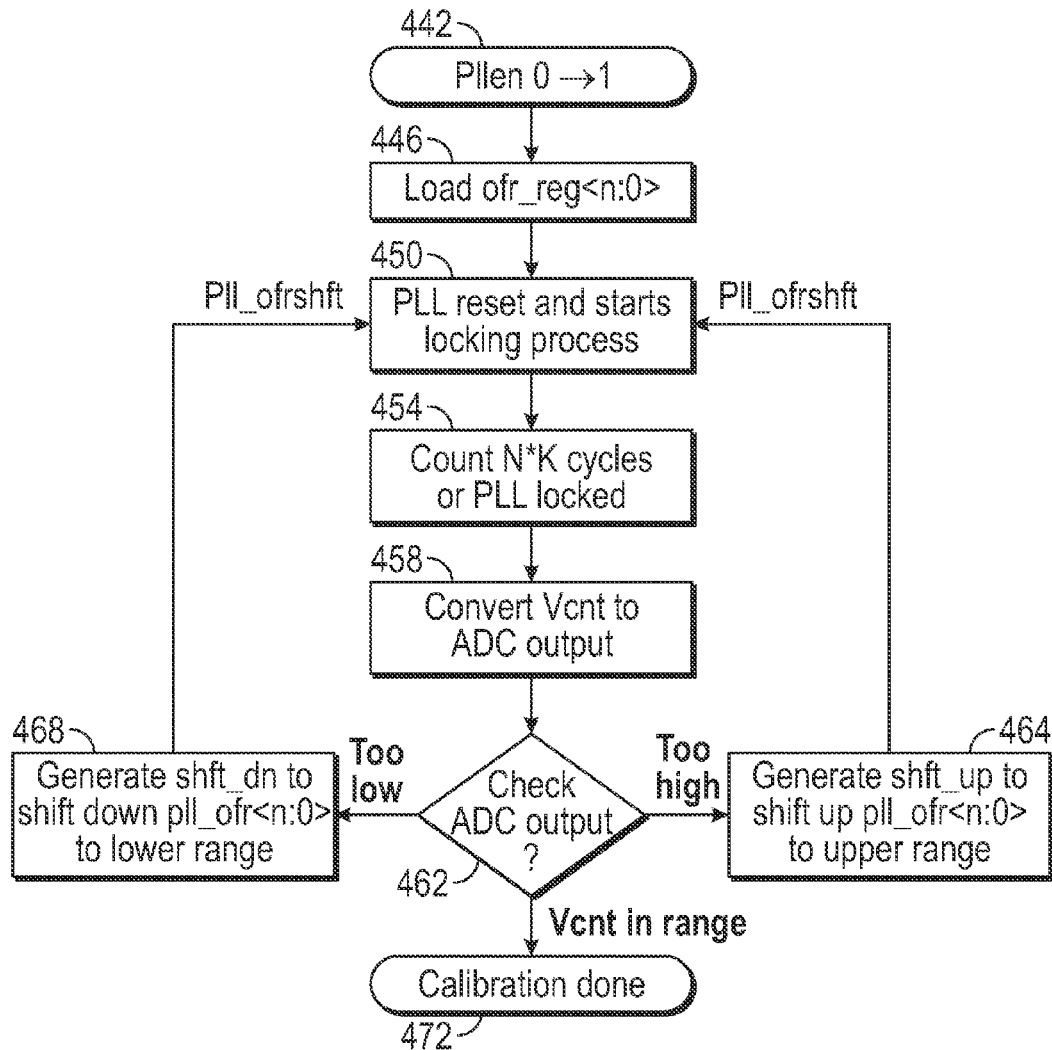


FIG. 8

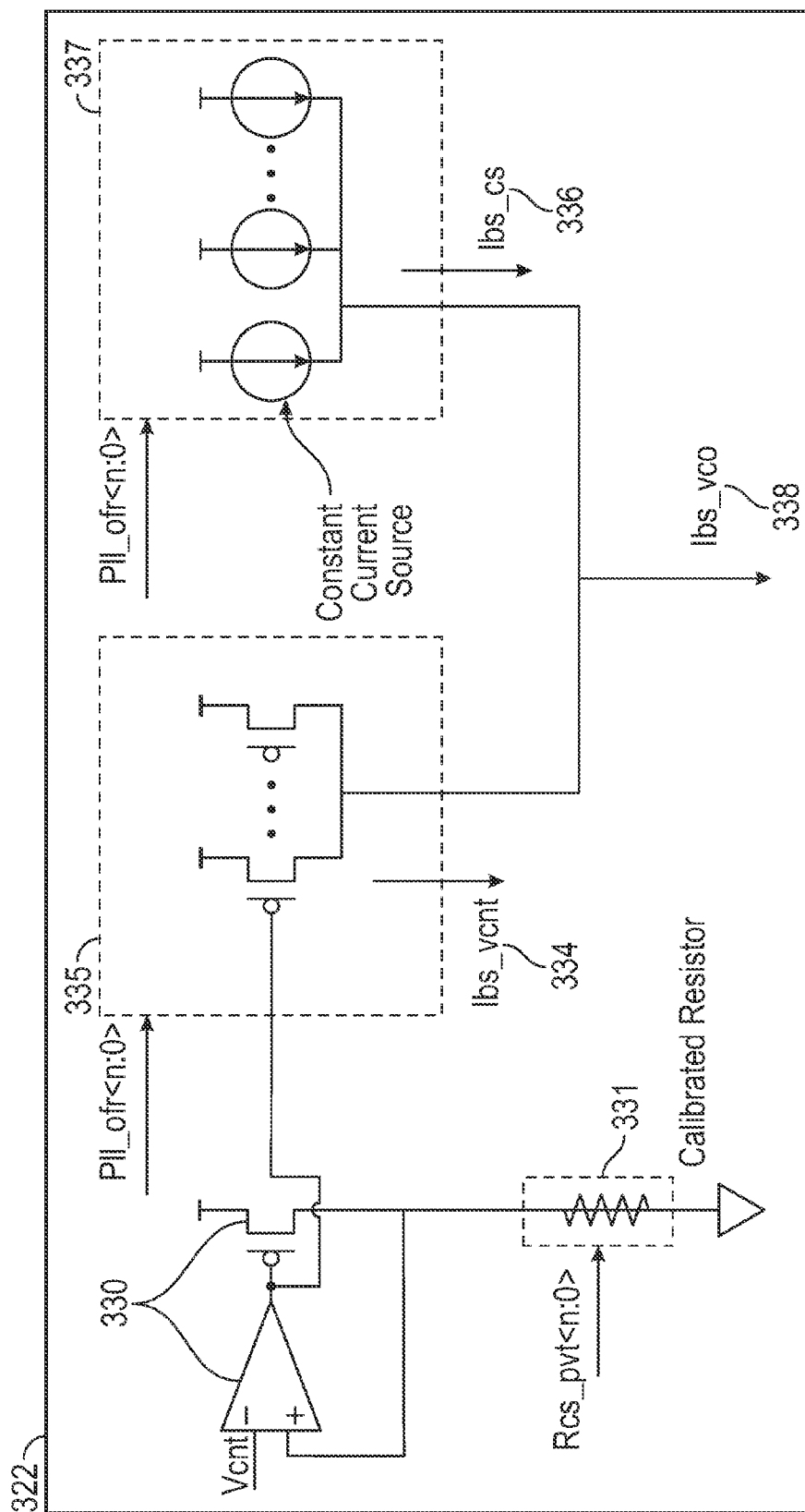


FIG. 9

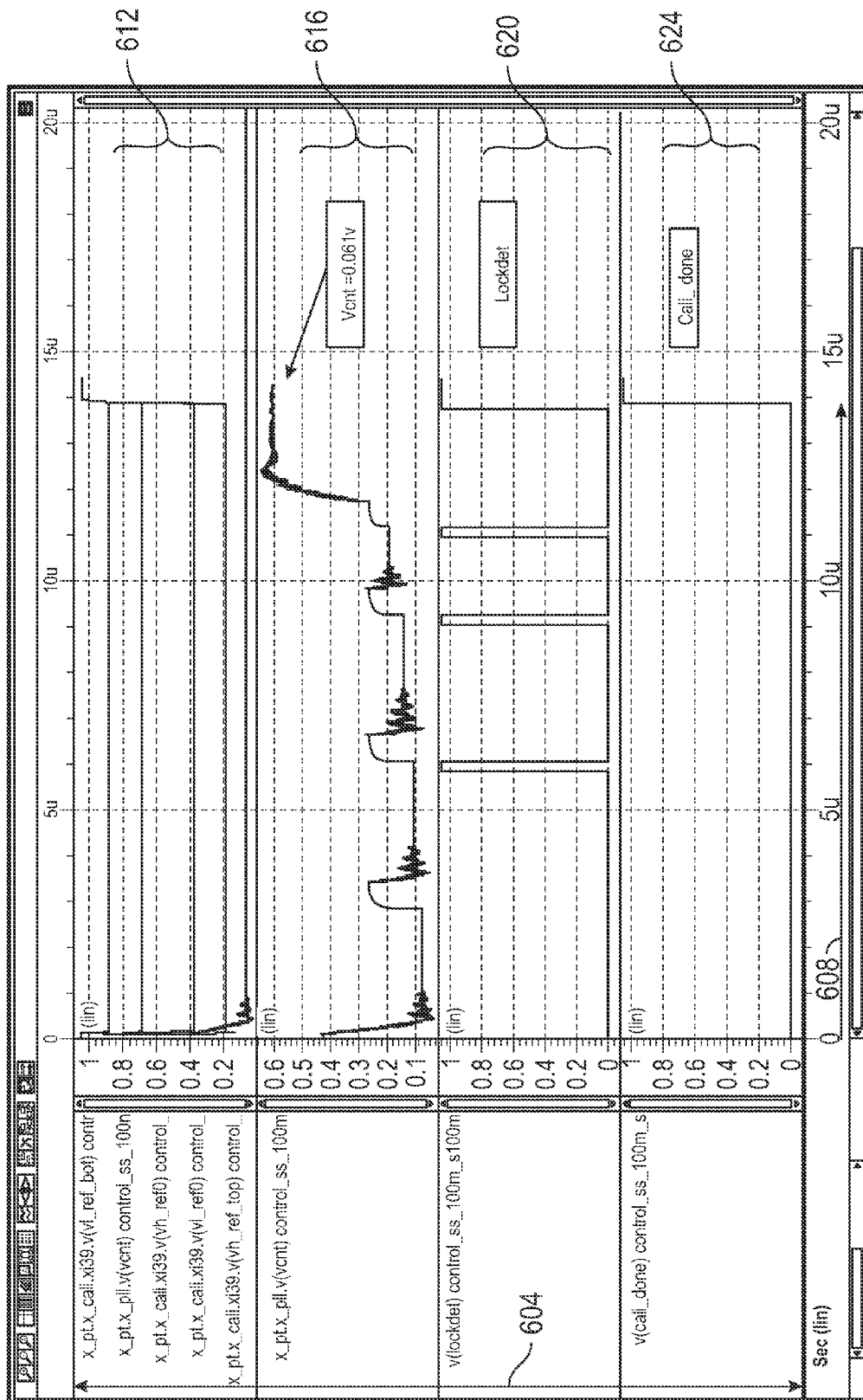
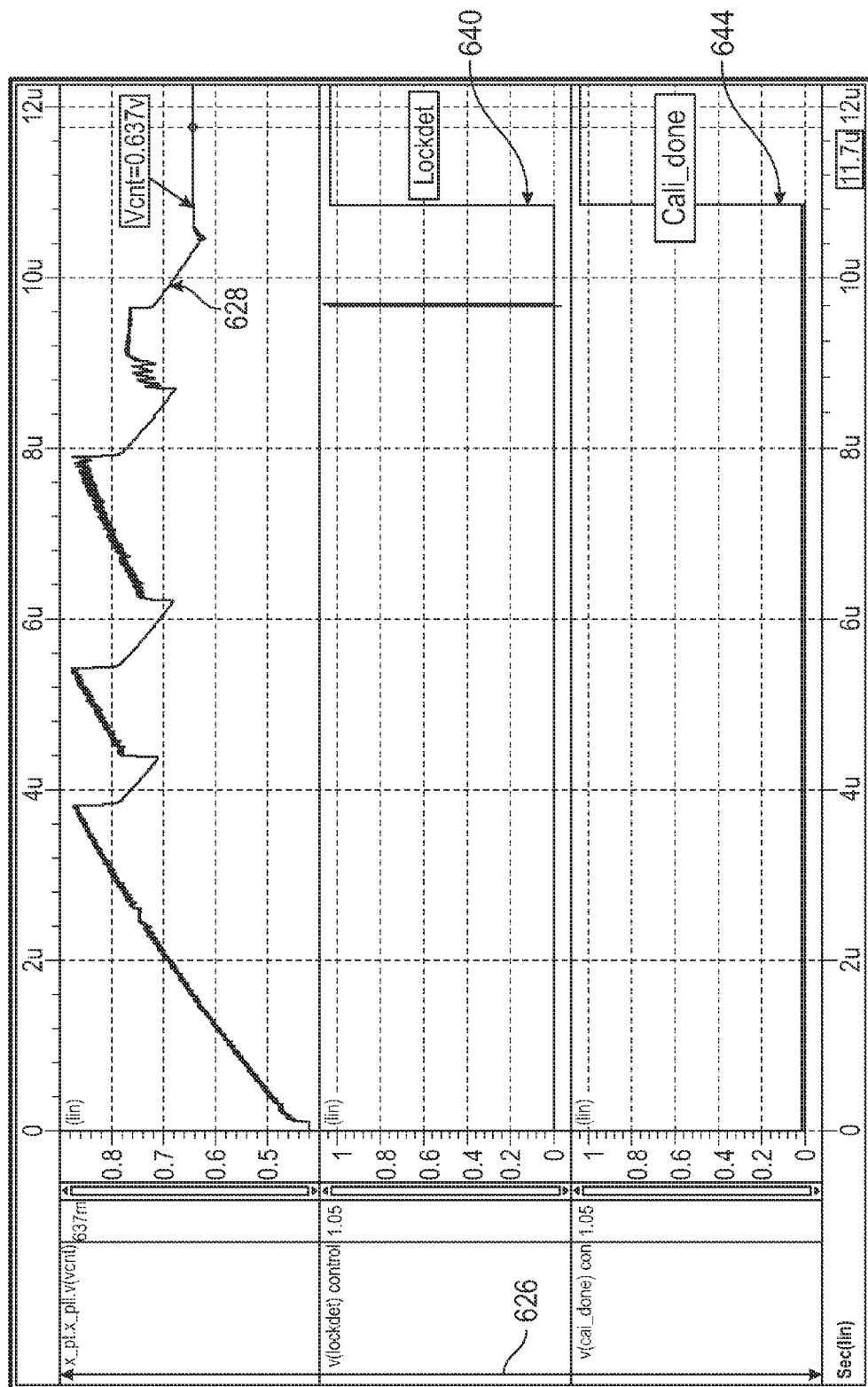


FIG. 10A



632 FIG. 10B

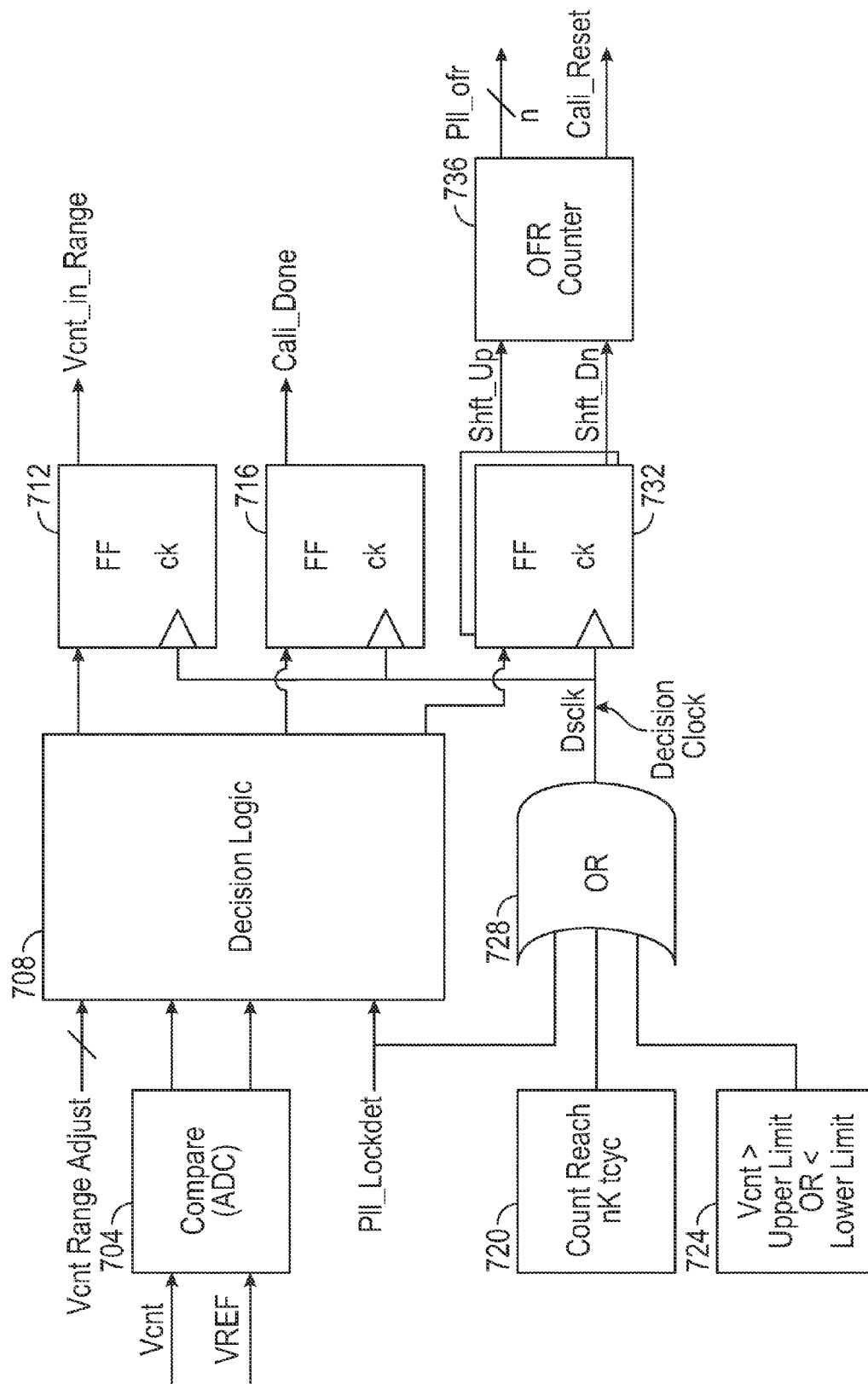


FIG. 11

# SYSTEMS AND METHODS OF PHASE-LOCKED LOOP INVOLVING CLOSED-LOOP, CONTINUOUS FREQUENCY RANGE, AUTO CALIBRATION AND/OR OTHER FEATURES

## CROSS-REFERENCE TO RELATED APPLICATION INFORMATION

This application claims benefit/priority of provisional patent application No. 61/783,374, filed Mar. 14, 2013, which is incorporated herein by reference in its entirety.

## BACKGROUND

### 1. Field

Aspects herein are directed to phase lock loop systems and methods involving circuitry with optimal operation ranges, improved performance at process corners, and/or reduced sensitivity to jitter.

### 2. Description of Related Information

Phase locked loop (PLL) circuits are widely used as clock generators for a variety of applications including microprocessors, wireless devices, serial link transceivers, and disk drive electronics, among others. FIG. 1 illustrates a block diagram of a typical charge-pump based PLL circuit design, including a Phase Frequency Detector (PFD) 108, Charge Pump (CP) 112, Loop Filter (LPF) 116, Voltage Control Oscillator (VCO) 120, and multiple Dividers 104, 128, 124.

Various existing phase lock loop circuits may be configured with a VCO that generates an output clock that is frequency-locked and phase aligned with the input clock by virtue of a negative feedback loop. According to such circuitry, the output clock frequency will be defined by the following equation when PLL is in lock condition:

$$CKOUT = CKIN * (N/M) * (1/P)$$

Further, in such embodiments, a typical VCO operates in a certain frequency range that will determine the PLL operating frequency range. The frequency of the VCO is controlled by V<sub>cnt</sub>, the input voltage to the VCO. FIG. 2A shows a typical input voltage V<sub>cnt</sub> versus VCO frequency, V-F curve. This VCO V-F curve will vary for different process corners. For example, for a slow process corner 224, the VCO frequency may be lower for the same V<sub>cnt</sub> voltage. And for a fast process corner 228, the VCO frequency may be higher for the same V<sub>cnt</sub> voltage. In other words, to maintain the same output frequency, a slow corner will require a higher V<sub>cnt</sub>, and a fast corner will require a lower V<sub>cnt</sub>. Moreover, there is a limited operating voltage range for V<sub>cnt</sub> which is defined by the V<sub>cnt</sub>(min) and the V<sub>cnt</sub>(max). Therefore, it is very important to keep V<sub>cnt</sub> within its operating voltage range for any process corner.

The frequency limit, freq\_max 212, is highest frequency that VCO can generate, and the minimum frequency, freq\_min 216, is the lowest frequency VCO can generate. As such, the VCO gain of FIG. 2A, K<sub>vco</sub>, may be given by the following equation:

$$K_{vco} = \Delta F / \Delta V = (freq\_max - freq\_min) / (V_{cnt\_max} - V_{cnt\_min})$$

If VCO gain (K<sub>vco</sub>) is very large, then any small amount of change in input voltage V<sub>cnt</sub> will translate into a big frequency disturbance at the VCO output, which will eventually show as jitter at the final output clock, CKOUT. Therefore, it is undesirable to design a VCO with a K<sub>vco</sub> value that is too large such as 232 in FIG. 2A. If a circuit's frequency range is

not expansive enough to cover the required range of operating frequencies, then a designer will have to increase the VCO gain to have steeper V-F curve such that it can cover the much higher and/or lower operating frequencies.

Turning to illustrative operation of the implementations shown in FIG. 2A, FIG. 2B is a timing diagram illustrating input voltage V<sub>cnt</sub> required for high frequency operation curve 236 and a low frequency operation curve 240. Here, an input voltage V<sub>cnt</sub> 234 of a very high value (0.94 v) may be required, e.g. at 244, for the VCO to generate a high frequency clock output at a slow process corner. Conversely, an input voltage V<sub>cnt</sub> of a very low value (0.12 v) may be required, e.g. at 248, for low frequency clock output at fast process corner. Such restrictions may severely push the headroom for the charge pump circuitry, and cause large current mismatch between charging current I<sub>p</sub> and discharging current I<sub>n</sub>. To avoid drawbacks such as the above-mentioned charge-pump current mismatch, it is desirable to keep the V<sub>cnt</sub> operating near the middle range of power supply voltage (VDD) at any process corners.

## OVERVIEW OF SOME ASPECTS

For example, various systems and methods consistent with aspects of the present inventions may involve PLL circuitry wherein associated voltage controlled oscillator components operate at an optimal range such that the control voltage, V<sub>cnt</sub>, will always settle near the middle of supply voltage (VDD) for any process corners. Further, as a function of utilization of a plurality of operating frequency range settings, the slope of the plural associated V-F curves (represented by VCO gain K<sub>vco</sub>) are also kept small enough to reduce the sensitivity of PLL jitter due to any fluctuation at V<sub>cnt</sub>.

It is to be understood that both the foregoing general description and the following detailed description are exemplary and explanatory only and are not restrictive of the invention, as described. Further features and/or variations may be provided in addition to those set forth herein. For example, the present invention may be directed to various combinations and subcombinations of the disclosed features and/or combinations and subcombinations of several further features disclosed below in the detailed description.

## DESCRIPTION OF THE DRAWINGS

The accompanying drawings, which constitute a part of this specification, illustrate various implementations and aspects of the innovations herein and, together with the description, help illustrate the principles of the present inventions. In the drawings:

FIG. 1 is a block diagram of a known phase lock loop.

FIG. 2A is a graph showing exemplary relationships of voltage against frequency in according to known voltage controlled oscillator (VCO) circuitry.

FIG. 2B is a graph showing an exemplary relationship of VCO input voltage against frequency in illustrative VCO circuitry.

FIG. 3 is a block diagram showing high-level, illustrative PLL circuitry consistent with certain aspects related to the innovations herein.

FIG. 4 is a block diagram showing illustrative calibration circuitry 316 of the PLL circuitry of FIG. 3, consistent with certain aspects related to the innovations herein.

FIGS. 5-6 are block diagrams illustrating exemplary PLL circuitry associated with FIG. 4 and closed-loop continuous



auto calibration features consistent with certain aspects related to the innovations herein.

FIG. 7 is a graph showing exemplary relationships of voltage against frequency in illustrative voltage controlled oscillator (VCO) circuitry, consistent with certain aspects related to the innovations herein.

FIG. 8 is a flow diagram illustrating an exemplary auto-calibrating PLL algorithm consistent with certain aspects related to the innovations herein.

FIG. 9 is a block diagram illustrating further detailed PLL circuitry having closed-loop continuous auto calibration consistent with certain aspects related to the innovations herein.

FIG. 10A is a graph illustrating exemplary operating frequency range auto-calibration waveforms of the present PLLs, shifting down, consistent with certain aspects related to the innovations herein.

FIG. 10B is a graph illustrating exemplary operating frequency range auto-calibration waveforms of the present PLLs, shifting up, consistent with certain aspects related to the innovations herein.

FIG. 11 is block diagram illustrating exemplary operating frequency range calibration circuitry of the present PLLs, consistent with certain aspects related to the innovations herein.

#### DETAILED DESCRIPTION OF ILLUSTRATIVE IMPLEMENTATIONS

Reference will now be made in detail to the inventions herein, examples of which are illustrated in the accompanying drawings. The implementations set forth in the following description do not represent all implementations consistent with the claimed inventions. Instead, they are merely some examples consistent with certain aspects related to the present innovations. Wherever possible, the same reference numbers will be used throughout the drawings to refer to the same or like parts.

Various representative systems and methods involving the present phase lock loop innovations are shown in FIGS. 3-11. Consistent with implementations herein, PLL circuitry including voltage controlled oscillator (VCO) circuitry may be configured to operate in several different frequency ranges. FIG. 3 is a block diagram illustrating such PLL circuitry having closed-loop continuous auto calibration consistent with certain aspects related to the innovations herein. Referring to FIG. 3, an illustrative phase lock loop circuit is shown, comprising a center voltage V<sub>cnt</sub> line 312, a filter 308 such as a low pass filter, VCO-related circuitry 320, and calibration circuitry 316. In illustrative implementations, such calibration circuitry may comprise various subcircuitry 326, for example, input voltage (V<sub>cnt</sub>) compare circuitry including analog-to-digital converter (ADC) circuitry, decision circuitry and control circuitry such as Operating Frequency Range (OFR) counter circuitry.

Here, for example, at a first operating frequency range for the OFR counter circuitry, calibration circuitry 316 may be configured to monitor and detect the input voltage and determine whether or not V<sub>cnt</sub> is within the desired range. If V<sub>cnt</sub> is out of its desired range, either too high or too low, then the OFR counter will shift up or down, respectively. Further, the PLL circuitry may be configured with Voltage-to-Current converter (VTC) circuitry 322 inside of or associated with the VCO circuitry 320 that will change the bias current based on the OFR counter, and thus shift the VCO to operate at the appropriate frequency, such as the next adjacent frequency range, at which time a calibration complete signal 332 may be provided. The phase lock loop circuitry may then be config-

ured to reset (e.g., V<sub>cnt</sub> may be reset to a specific voltage, such as ½ V<sub>DD</sub>) and start another closed-loop calibration procedure. Here, for example, such reset process may be initiated via a calibration reset signal 334. In some implementations, this calibration procedure may be an automatic process and may continue until the V<sub>cnt</sub> is within the desired range. When within range, a control voltage (V<sub>cnt</sub>) in-range signal 336 may be provided as output. Moreover, such auto calibration may be done in a closed-loop, continuous fashion. Various exemplary OFR auto-calibration waveforms of certain phase lock loop innovations are shown and described in more detail in connection with FIG. 6A and FIG. 6B, below.

FIGS. 4-6 are block diagrams illustrating exemplary calibration circuitry 316 having closed-loop continuous auto calibration consistent with certain aspects related to the innovations herein. One representative implementation of calibration circuitry 316 is shown in FIG. 4, including compare circuitry 408, decision/shift circuitry 416 and control circuitry 428 such as OFR counter circuitry. More detailed, illustrative implementations of such circuitry is shown in FIGS. 5 and 6.

Referring to FIG. 5, a first portion of exemplary calibration circuitry 316 and associated connections are shown, including the compare circuitry 408 and the decision/shift circuitry 416. Compare circuitry 408 may be configured to monitor and detect the input voltage and determine whether or not V<sub>cnt</sub> is within the desired range. If V<sub>cnt</sub> is out of its desired range, either too high or too low, appropriate processing is performed in the decision/shift circuitry 416 to instruct the control/counter circuitry to shift up or to shift down, respectively. In addition to the V<sub>cnt</sub> level, compare circuitry may have inputs receiving input signals from, inter alia, the PLL core 412, such as Bandgap voltage V<sub>bg</sub> 502, lock detect 504, and V<sub>cnt</sub> 312. If V<sub>cnt</sub> is detected to be out of range, such as when the operating frequency range is too low, the compare circuitry may send a low signal 506 to the decision/shift circuitry 416. Upon receipt of such signal, the decision/shift circuitry 416 may effect a switch up to a higher operating frequency range, such as via reset of V<sub>cnt</sub> to V<sub>dda</sub>/2, to avoid the VCO from running too fast. The decision/shift circuitry 416 may include various additional inputs, such as a V<sub>cnt</sub> high input, lock detect, an operating frequency range calibration check 510, an operating frequency range count control 512, and an operating frequency range calibration range control 514, among others. The decision/shift circuitry may include various outputs, such as shift up 516, shift down 518 and an operating frequency range control clock 520 provided to the control/counter circuitry 428, as well as a PLL operating frequency shift 522 and the V<sub>cnt</sub> in range 336 and calibration complete 332 outputs noted above. Further, the calibration circuitry 316 may also be configured to perform such operating frequency range adjustments after the PLL has started a locking procedure. Here, for example, the decision/shift circuitry 416 still uses the compare circuitry 408 results to determine a shift up or a shift down, though the calibration circuitry 316 is further configured, via OFR counter circuitry 428, to generate an OFR shift signal (pll\_ofrshft) 429 back to the PLL core to restart locking.

Turning to FIG. 6, connections and interaction between as well as to and from the decision/shift circuitry 416 and the control/counter circuitry 428 are shown. Here, for example, outputs from the decision/shift circuitry 416 such as shift up 516, shift down 518, and operating frequency range control clock 520, may be provided to the control/counter circuitry 428. In turn, the OFR counter circuitry 428 may provide control signals to external circuitry, including operating frequency range control signals 432 to the PLL core and to the

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VCO circuitry and/or VTC circuitry, among others. The operating frequency range control signals are utilized to operate the VCO to function at one of a plurality of gain levels, with the slope of such V-F curves being configured to provide the desired frequency for the available/established input voltage Vcnt range, with minimum jitter.

Further aspects and details involving calibration circuitry 316 configuration and operation are set forth in connection with FIGS. 8-9, 10A-10B and 11, below.

FIG. 7 is a graph showing exemplary relationships of voltage 480 against frequency 481 (V-F) curves in illustrative voltage controlled oscillator (VCO) circuitry, consistent with certain aspects related to the innovations herein. Referring to FIG. 7, five V-F curves 482, 484, 486, 488, 490 are shown for the purpose of illustration, however implementations herein may be configured with greater or fewer quantities of such operating frequency ranges. Specifically, as depicted in the illustrative graph of FIG. 7, a lowest OFR range (OFR<sub>0</sub>) 482 is shown, configured to provide the lowest range of VCO frequency for the corresponding voltage, Vcnt. Similarly, FIG. 4D also illustrates a highest OFR range (OFR<sub>n</sub>) 490 configured to provide the highest range of VCO frequency for the corresponding Vcnt operating voltage range, as well as a variety of intermediate OFR ranges 484, 486, 488. By means of shifting the VCO to the most suitable frequency range, among these, the PLL may iteratively perform its closed loop calibration processes until Vcnt is within the desired range. In some implementations, for example, circuitry may be configured such that the final Vcnt is settled near ½ VDD for any process corner.

FIG. 8 is a flow diagram illustrating an exemplary auto-calibration algorithm consistent with certain circuitry and aspects related to the innovations herein. The process shown in FIG. 8 begins with a PLL enable command 442 initiating the PLL locking procedure to seek a phase lock condition. At 446, an operating frequency range value (e.g., register ofr\_reg<n:0>) may then be loaded as the initial operating frequency range inside the PLL. A PLL reset signal may then be executed, at 450, to start the locking process. Next, at 454, the algorithm may wait a certain time or settling period of the locking process, i.e., a wait period such as a specified count of the calibration clock or once certain circuit condition(s) are satisfied such as when PLL lock is achieved or Vcnt is too high or too low for a long period of time. After this wait period, at 458, the algorithm and circuitry may then convert Vcnt through an Analog-to-Digital Converter (ADC) with reference voltages such as vh\_refs and vl\_refsgenerated, e.g., from Bandgap voltage VBG (or power supply VDD) and resistors divider circuitry. Then, at 462, a Vcnt level check is performed to determine if the ADC output (Vcnt) is within an acceptable range or if it is too high or too low. If ADC output (Vcnt) is within an acceptable range, the calibration process is completed, at 472. If, however, ADC output is determined to be too low, the circuitry will generate a shift down signal (shift\_dn), at 468, to shift the PLL operating frequency range to a lower level. From there, a new PLL reset is initiated and the algorithm returns to the start of a new locking process, at 450. If, at the Vcnt level check 462, ADC output is determined to be too high, the circuitry will generate a shift up signal (shift\_up), at 464, to shift the PLL operating frequency range to a higher level, at 464. From there, a new PLL reset is initiated and the algorithm returns to the start of a new locking process.

FIG. 9 is a block diagram depicting illustrative circuit layout details of exemplary VTC circuitry 322, consistent with certain aspects related to the innovations herein. Referring to the representative circuitry shown in these figures, the

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Vcnt voltage may be converted to current via feedback circuitry 330 such as a feedback network and a calibrated resistor 331, as shown in more detail, for example, in FIGS. 5B2, 5C and 5D of the priority/provisional application incorporated by reference herein and attached hereto as an Appendix. The resistor may be calibrated and may be held constant over different Process, Voltage, and Temperature (PVT). In following circuitry 334, the current ibs\_vcnt is combined with another constant current source ibs\_cs, from 336, to generate the bias current signal for the VCO 338 (ibs\_vco). Further, according to some implementations, a group of vcnt-generated current sources 335 and a group of constant current sources 337 may be one or both of adjustable and/or programmable through ofr<n:0> during the PLL OFR calibration process.

FIG. 10A is a graph illustrating exemplary operating frequency range auto-calibration waveforms (voltage 604 against time 608) of PLL circuitry, during shift down operation of OFR calibration, consistent with certain aspects related to the innovations herein. As illustrated in FIG. 10A, the graph of Vcnt over time 616 is shown in association with PLL/calibration signals 612, the PLL lock detect signal 620 and the resulting calibration done signal 624. Consistent with the innovations herein, a Vcnt signal beginning at less than 0.1 v settles near the middle of the supply voltage, at 0.61 v. FIG. 10B is a graph illustrating exemplary operating frequency range auto-calibration waveforms (voltage 626 against time 632) of the present PLLs, during shift up operation of OFR calibration, consistent with certain aspects related to the innovations herein. As illustrated in FIG. 10B, the graph of Vcnt over time 628 is shown in association with the PLL lock detect signal 640 and the resulting calibration done signal 644. Consistent with the innovations herein, a Vcnt signal rising to a level as high as 0.85 v settles near the middle of the supply voltage, at 0.637 v. Again, in the presently-described implementation, as illustrated here, a VDD of 1.2 v and associated levels are set forth, however various other values and permutations are of course feasible under the innovations herein.

As set forth above and shown graphically in FIG. 10A and FIG. 10B, the present invented PLL will continuously search for the optimal Operating Frequency Range (OFR) for the VCO and make sure that the final Vcnt is settled near ½ VDD for any process corner (again, above VDD=1.2 v for the illustrated embodiments). Present implementations may also dramatically reduce the mismatch between the charge pump currents Ip and In, and improve the PLL jitter performance. Further, in accordance with certain implementations, the total number of iterations for OFR calibration can be limited to, e.g., N times. In such implementations, the PLL OFR calibration will stop once the maximum number of calibration has been reached. Here, then, the desired Vcnt range may be adjustable and may be set to a widest range at the last iteration of calibration.

FIG. 11 is block diagram illustrating exemplary operating frequency range calibration circuitry of the present PLLs, consistent with certain aspects related to the innovations herein. In addition to compare circuitry 704, decision/shift circuitry 708 and OFR counter circuitry 736, which may be consonant with the circuitry 408, 416, 428 shown and described in connection with FIGS. 4-9, illustrative circuitry of FIG. 11 may include count circuitry 720 involved with reaching the specified wait period, limit circuitry 724 involved with determinations as to whether Vcnt is above or below the desired limits, as well as other logic 728 and/or flip-flops 712, 716, 732 involved with establishing or convey-

ing associated signals such as the decision clock, V<sub>cnt</sub> in range, calibration done, shift up, shift down, or other signaling.

Accordingly, via the circuitry and configurations above, optimal overall performance of a PLL with the closed-loop, continuous auto-calibration for the various levels of operating frequency range may be achieved consistent with one or more aspects of the present innovations.

In addition to the above innovations and architecture, the present inventions also include, inter alia, methods of operation, methods of fabricating devices consistent with the features and/or functionality herein, products, and products produced via such processes. By way of example and not limitation, methods of fabrication herein may include known manufacturing processes such as in CMOS technologies involving aspects such as p-mos and n-mos transistor formation, multiple metallization layers and/or local interconnects, among others. A variety of exemplary/staple processes here, for example, being set forth in the backgrounds/disclosures of U.S. Pat. Nos. 4,794,561, 5,624,863, 5,994,178, 6,001,674, 6,117,754, 6,127,706, 6,417,549, 6,894,356, and 7,910,427 as well as U.S. patent application publication No. US2007/0287239A1, which are incorporated herein by reference.

As disclosed herein, features consistent with the present inventions may be utilized via and/or involved with various circuits/circuitry, hardware, software and/or firmware. For example, the systems and methods disclosed herein may be embodied in or used in connection with various forms including, for example, memory, data processors, such as in computing devices that also includes memory, a database, digital electronic circuitry, firmware, software, or in combinations of them. Further, while some of the disclosed implementations describe specific hardware components, systems and methods consistent with the innovations herein may be implemented in the context of any combination of hardware, software and/or firmware. Moreover, the above-noted features and other aspects and principles of the innovations herein may be implemented in various memory environments. Such environments and related applications may be specially constructed for performing the various routines, processes and/or operations according to the invention or they may include a general-purpose computer or computing platform selectively activated or reconfigured by code to provide the necessary functionality. The processes disclosed herein are not inherently related to any particular computer, network, architecture, environment, or other apparatus, and may be implemented by a suitable combination of hardware, software, and/or firmware. For example, various general-purpose machines may be used with programs written in accordance with teachings of the invention, or it may be more convenient to construct a specialized apparatus or system to perform the required methods and techniques.

Aspects of the method and system described herein, such as the logic, may be implemented as functionality programmed into any of a variety of circuitry, including programmable logic devices ("PLDs"), such as field programmable gate arrays ("FPGAs"), programmable array logic ("PAL") devices, electrically programmable logic and memory devices and standard cell-based devices, as well as application specific integrated circuits. Some other possibilities for implementing aspects include: memory devices, microcontrollers with memory (such as EEPROM), embedded microprocessors, firmware, software, etc. Furthermore, aspects may be embodied in microprocessors having software-based circuit emulation, discrete logic (sequential and combinatorial), custom devices, fuzzy (neural) logic, quantum devices, and hybrids of any of the above device types.

The underlying device technologies may be provided in a variety of component types, e.g., metal-oxide semiconductor field-effect transistor ("MOSFET") technologies like complementary metal-oxide semiconductor ("CMOS"), bipolar technologies like emitter-coupled logic ("ECL"), polymer technologies (e.g., silicon-conjugated polymer and metal-conjugated polymer-metal structures), mixed analog and digital, and so on.

It should also be noted that the various logic and/or functions disclosed herein may be enabled using any number of combinations of hardware, firmware, and/or as data/instructions embodied in various machine-readable or computer-readable media, in terms of their behavioral, register transfer, logic component, and/or other characteristics. Computer-readable media in which such formatted data and/or instructions may be embodied include, but are not limited to, non-volatile storage media in various forms (e.g., optical, magnetic or semiconductor storage media), though does not include transitory media such as carrier waves.

Unless the context clearly requires otherwise, throughout the description and the claims, the words "comprise," "comprising," and the like are to be construed in an inclusive sense as opposed to an exclusive or exhaustive sense; that is to say, in a sense of "including, but not limited to." Words using the singular or plural number also include the plural or singular number respectively. Additionally, the words "herein," "hereunder," "above," "below," and words of similar import refer to this application as a whole and not to any particular portions of this application. When the word "or" is used in reference to a list of two or more items, that word covers all of the following interpretations of the word: any of the items in the list, all of the items in the list and any combination of the items in the list.

Although certain presently preferred implementations of the invention have been specifically described herein, it will be apparent to those skilled in the art to which the inventions pertain that variations and modifications of the various implementations shown and described herein may be made without departing from the spirit and scope of the innovations herein. Accordingly, it is intended that the inventions be limited only to the extent required by the applicable rules of law.

The invention claimed is:

1. A circuit device comprising:

voltage controlled oscillator (VCO) circuitry; calibration circuitry including frequency range shift circuitry, the calibration circuitry having an input receiving an input voltage and an output outputting a shift signal shifting an operating frequency range of the voltage control oscillator circuitry to a different operating frequency range based on the input voltage to provide closed-loop calibration;

voltage-to-current converter circuitry that changes a bias current of the voltage controlled oscillator circuitry based on the frequency range shift circuitry.

2. The device of claim 1, further comprising: voltage compare circuitry receiving the input voltage.

3. The device of claim 2, further comprising: shift circuitry determining the operating frequency range based on an output of the voltage compare circuitry.

4. The device of claim 3, further comprising: counter circuitry shifting an operating state up or down based on an output of the shift circuitry.

5. The device of claim 4, wherein the counter circuitry shifts the operating frequency range.

6. The device of claim 1, wherein the VCO circuitry selectively operates in a plurality of operating frequency ranges.

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7. The device of claim 1, wherein the VCO circuitry generates an output clock that is frequency locked and phase aligned with an input clock.

8. The device of claim 1, further comprising:  
charge pump circuitry that outputs the input voltage to the VCO circuitry and the calibration circuitry.

9. The device of claim 1, further comprising:  
low pass filter circuitry provided between the charge pump circuitry and the VCO circuitry.

10. The device of claim 1, wherein shifting the operating frequency range is performed after the device has started a phase lock process.

11. The device of claim 1 wherein the circuitry is configured to shift the VCO circuitry to different operating frequency ranges and provide continuous frequency range auto-calibration.

12. The device of claim 1 wherein the calibration circuitry reduces jitter at output clock circuitry.

13. The device of claim 1 wherein the calibration circuitry reduces current mismatch between a charging current and a discharging current.

14. The device of claim 1 wherein the calibration circuitry comprises circuitry that determines whether the input voltage is within a predetermined range.

15. The device of claim 14 wherein the calibration circuitry outputs the signal shifting the operating frequency range when the input voltage is outside the predetermined range.

16. The device of claim 1 wherein the calibration circuitry calibrates until the input voltage is approximately half a supply voltage.

17. The device of claim 1 wherein the bias current change shifts the operating frequency range of the VCO circuitry.

18. The device of claim 1 wherein the calibration circuitry resets the input voltage after shifting the operating frequency range.

19. The device of claim 1 wherein a signal generated by decision circuitry instructs the frequency range shift circuitry to shift up/down the operating frequency range of the VCO circuitry.

20. The device of claim 1 wherein the frequency range shift circuitry generates a shift signal to PLL core circuitry to restart locking.

21. The device of claim 1 further comprising:  
counter circuitry counting a number of operating frequency range shifts.

22. The device of claim 1 wherein the frequency range shift circuitry includes operating frequency range counter circuitry.

23. The device of claim 1 wherein the frequency range shift circuitry outputs an operating frequency range control signal to operate the VCO circuitry at one of a plurality of gain levels or operating frequency ranges.

24. The device of claim 1 wherein decision circuitry generates a calibration complete signal when the input voltage is within a predetermined range.

25. The device of claim 24 wherein the decision circuitry generates a frequency range shift count.

26. The device of claim 1 wherein the operating frequency range is shifted iteratively by the calibration circuitry until the input voltage is within a predetermined range.

27. A circuit device comprising:  
oscillator circuitry having an input that receives an input voltage;

calibration circuitry having frequency range shift circuitry and an output that provides a signal to the oscillator circuitry, the calibration circuitry receiving the input voltage and providing closed-loop calibration by output-

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ting the signal that shifts an operating frequency range of the oscillator circuitry to a different operating frequency range based on the signal;

converter circuitry that changes a bias of the oscillator circuitry based on the signal from the frequency range shift circuitry.

28. The device of claim 27, wherein the oscillator circuitry further comprises:

third circuitry that changes the bias based on the signal from the calibration circuitry to shift the operating frequency range of the oscillator circuitry.

29. The device of claim 28 wherein the calibration circuitry outputs a shift up/shift down signal to the third circuitry.

30. The device of claim 28 wherein the third circuitry outputs operating frequency range signals to phase locked loop circuitry and voltage control oscillator circuitry.

31. The device of claim 27, wherein the oscillator circuitry receives input signals from phase locked loop circuitry.

32. The device of claim 31, wherein the input signals comprise a lock detect signal and the input voltage.

33. The device of claim 31, wherein the device is configured to shift the operating frequency range after the phase locked loop circuitry starts a locking procedure.

34. The device of claim 27, further comprising:  
third circuitry that shifts the operating frequency range up by resetting the input voltage.

35. The device of claim 27, wherein each of the plurality of operating frequency ranges represents a different voltage-frequency curve.

36. The device of claim 27, wherein the operating frequency range is selected such that the input voltage settles near half a supply voltage for any process corner.

37. The device of claim 27, further comprising:  
voltage compare circuitry receiving the input voltage.

38. The device of claim 37, further comprising:  
shift circuitry determining the operating frequency range based on an output of the voltage compare circuitry.

39. The device of claim 38, further comprising:  
counter circuitry shifting an operating state up or down based on an output of the shift circuitry.

40. The device of claim 39, wherein the counter circuitry shifts the operating frequency range.

41. The device of claim 27, wherein the oscillator circuitry selectively operates in a plurality of operating frequency ranges.

42. The device of claim 27 wherein the oscillator circuitry generates an output clock that is frequency locked and phase aligned with an input clock.

43. The device of claim 27 further comprising:  
charge pump circuitry that outputs the input voltage to the oscillator circuitry and the calibration circuitry.

44. The device of claim 27 further comprising:  
low pass filter circuitry provided between the charge pump circuitry and the oscillator circuitry.

45. The device of claim 27 wherein shifting the operating frequency range is performed after the device has started a phase lock process.

46. The device of claim 27 wherein the circuitry is configured to shift the oscillator circuitry to different operating frequency ranges and provide continuous frequency range auto-calibration.

47. The device of claim 27 wherein the calibration circuitry reduces jitter at output clock circuitry.

48. The device of claim 27 wherein the calibration circuitry reduces current mismatch between a charging current and a discharging current.

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49. The device of claim 27 wherein the calibration circuitry comprises circuitry that determines whether the input voltage is within a predetermined range.

50. The device of claim 49 wherein the calibration circuitry outputs the signal shifting the operating frequency range when the input voltage is outside the predetermined range.

51. The device of claim 27 wherein the calibration circuitry calibrates until the input voltage is approximately half a supply voltage.

52. The device of claim 27 wherein the bias current change shifts the operating frequency range of the oscillator circuitry.

53. The device of claim 27 wherein the calibration circuitry resets the input voltage after shifting the operating frequency range.

54. The device of claim 27 wherein a signal generated by decision circuitry instructs the frequency range shift circuitry to shift up/down the operating frequency range of the VCO circuitry.

55. The device of claim 27 wherein the frequency range shift circuitry generates a shift signal to PLL core circuitry to restart locking.

56. The device of claim 27 further comprising:  
counter circuitry counting a number of operating frequency range shifts.

57. The device of claim 27 wherein the frequency range shift circuitry includes operating frequency range counter circuitry.

58. The device of claim 27 wherein the frequency range shift circuitry outputs an operating frequency range control signal to operate the oscillator circuitry at one of a plurality of gain levels or operating frequency ranges.

59. The device of claim 27 wherein decision circuitry generates a calibration complete signal when the input voltage is within a predetermined range.

60. The device of claim 59 wherein the decision circuitry generates a frequency range shift count.

61. A circuit device comprising:

oscillator circuitry having an input that receives a shift signal;

calibration circuitry that receives an input signal, has an output that outputs the shift signal to the oscillator circuitry, and provides closed-loop, continuous calibration by outputting the shift signal which shifts an operating frequency range of the oscillator circuitry to a different operating frequency range based on the input signal, the calibration circuitry comprising:  
comparison circuitry comparing the input signal to a predetermined signal range; and  
decision circuitry generating a signal to frequency range shift circuitry based on a result of the comparison

circuitry; and  
frequency range shift circuitry that shifts the operating frequency range of the oscillator circuitry to another operating frequency range;

wherein the oscillator circuitry further comprises voltage-to-current converter circuitry changing a bias current based on the frequency range shift circuitry.

62. The device of claim 27 wherein the operating frequency range is shifted iteratively by the calibration circuitry until the input voltage is within a predetermined range.

63. The device of claim 61 wherein the oscillator circuitry further comprises:  
third circuitry that changes the bias current based on the signal from the calibration circuitry to shift the operating frequency range of the oscillator circuitry.

64. The device of claim 61 wherein the oscillator circuitry receives input signals from phase locked loop circuitry.

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65. The device of claim 64 wherein the input signals comprise a lock detect signal and the input voltage.

66. The device of claim 64 wherein the device is configured to shift the operating frequency range after the phase locked loop circuitry starts a locking procedure.

67. The device of claim 61 further comprising:  
third circuitry that shifts the operating frequency range up by resetting the input voltage.

68. The device of claim 61 wherein each of the plurality of operating frequency ranges represents a different voltage-frequency curve.

69. The device of claim 61 wherein the operating frequency range is selected such that the input voltage settles near half a supply voltage for any process corner.

70. The device of claim 61 further comprising:  
voltage compare circuitry receiving the input voltage.

71. The device of claim 70, further comprising:  
shift circuitry determining the operating frequency range based on an output of the voltage compare circuitry.

72. The device of claim 71, further comprising:  
counter circuitry shifting an operating state up or down based on an output of the shift circuitry.

73. The device of claim 72, wherein the counter circuitry shifts the operating frequency range.

74. The device of claim 61 wherein the oscillator circuitry selectively operates in a plurality of operating frequency ranges.

75. The device of claim 61 wherein the oscillator circuitry generates an output clock that is frequency locked and phase aligned with an input clock.

76. The device of claim 61 further comprising:  
charge pump circuitry that outputs the input voltage to the oscillator circuitry and the calibration circuitry.

77. The device of claim 61 further comprising:  
low pass filter circuitry provided between the charge pump circuitry and the oscillator circuitry.

78. The device of claim 61 wherein shifting the operating frequency range is performed after the device has started a phase lock process.

79. The device of claim 61 wherein the circuitry is configured to shift the oscillator circuitry to different operating frequency ranges and provide continuous frequency range auto-calibration.

80. The device of claim 61 wherein the calibration circuitry reduces jitter at output clock circuitry.

81. The device of claim 61 wherein the calibration circuitry reduces current mismatch between a charging current and a discharging current.

82. The device of claim 61 wherein the calibration circuitry comprises circuitry that determines whether the input voltage is within a predetermined range.

83. The device of claim 82 wherein the calibration circuitry outputs the signal shifting the operating frequency range when the input voltage is outside the predetermined range.

84. The device of claim 61 wherein the calibration circuitry calibrates until the input voltage is approximately half a supply voltage.

85. The device of claim 61 wherein the bias current change shifts the operating frequency range of the oscillator circuitry.

86. The device of claim 61 wherein the calibration circuitry resets the input voltage after shifting the operating frequency range.

87. The device of claim 61 wherein a signal generated by decision circuitry instructs the frequency range shift circuitry to shift up/down the operating frequency range of the VCO circuitry.

88. The device of claim 61 wherein the frequency range shift circuitry generates a shift signal to PLL core circuitry to restart locking.

89. The device of claim 61 further comprising:  
counter circuitry counting a number of operating frequency range shifts.

90. The device of claim 61 wherein the frequency range shift circuitry includes operating frequency range counter circuitry.

91. The device of claim 61 wherein the frequency range shift circuitry outputs an operating frequency range control signal to operate the oscillator circuitry at one of a plurality of gain levels or operating frequency ranges.

92. The device of claim 61 wherein decision circuitry generates a calibration complete signal when the input voltage is within a predetermined range.

93. The device of claim 92 wherein the decision circuitry generates a frequency range shift count.

94. The device of claim 61 wherein the operating frequency range is shifted iteratively by the calibration circuitry until the input voltage is within a predetermined range.

95. The device of claim 61 wherein the comparison circuitry receives an input signal from PLL core circuitry including a lock detect signal.

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